



Data Sheet

16 AMPERES COMPLEMENTARY SILICON POWER TRANSISTORS 250 VOLTS, 200 WATTS, Bipolar Transistors 16A 250V 200W NPN

Manufacturers ON Semiconductor, LLC

Package/Case TO-247

Product Type Transistors

RoHS Rohs

Lifecycle



Images are for reference only

ONSEMI

Please submit RFQ for MJW21196G or Email to us: sales@ovaga.com We will contact you in 12 hours.

<u>RFQ</u>

General Description

The MJW21196 NPN Bipolar Complementary Audio Power Transistor utilizes Perforated Emitter technology and is specifically designed for high power audio output, disk head positioners and linear applications.

Features Application

Total Harmonic Distortion Characterized

High DC Current Gain = 8 Adc

Excellent Gain Linearity

High SOA: 2.25 A, 80 V, 1 Second

Pb-Free Packages are Available



Related Products



MJE172
ON Somioond

ON Semiconductor, LLC TO-126



MJD42CT4G

ON Semiconductor, LLC SOT25



MJL21195G

ON Semiconductor, LLC TO-3PL



MJ4502G

ON Semiconductor, LLC TO-204-2 (TO-3)



MJE350G

ON Semiconductor, LLC TO-126



MJD44H11-1G

ON Semiconductor, LLC TO-251



MJ802G

ON Semiconductor, LLC TO-204-2



MJH6287

ON Semiconductor, LLC TO-247